



FCX493Q

#### 100V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT89

#### **Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

#### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound
- Moisture Sensitivity: Level 1 per J-STD-020
- UL Flammability Rating 94V-0
- Terminals: Matte Tin Finish, Solderable per MIL-STD-202, Method 208 (©3)
- Weight: 0.052 grams (Approximate)

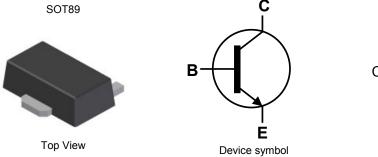
#### **Features**

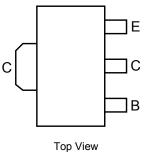
- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 1A high Continuous Current
- Low saturation voltage V<sub>CE(sat)</sub> < 300mV @ 250mA</li>
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The FCX493Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Application**

- Load management functions
- Solenoid, relay and actuator drivers
- DC DC modules





Pin-Out

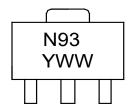
#### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX493QTA	Automotive	N93	7	12	1000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



N93 = Product Type Marking Code YWW - Date Code Y - Last digit of year (ex: 0 = 2020) WW - Week code (01~53)



# Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	120	V
Collector-Emitter Voltage	$V_{CEO}$	100	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I <sub>CM</sub>	2	Α
Continuous Base Current	Ι <sub>Β</sub>	200	mA

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector Power Dissipation (Note 5)	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta JL}$	10.01	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

#### ESD Ratings (Note 7)

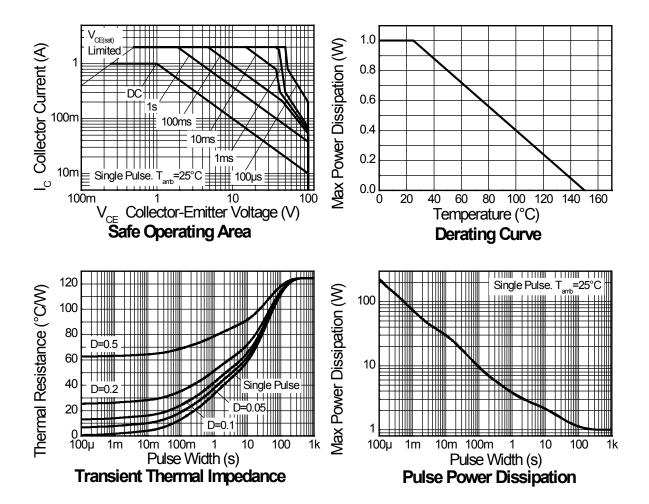
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- 6. Thermal resistance from junction to solder-point (on the exposed collector pad).
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



#### **Thermal Characteristics and Derating Information**





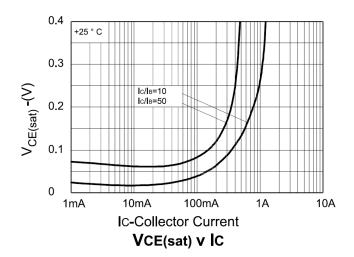
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

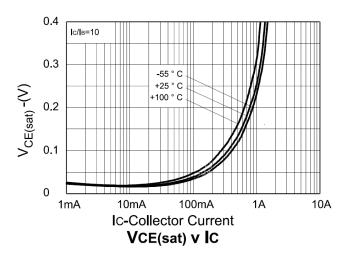
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	120	-	-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	$BV_{CEO}$	100	-	-	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	-	-	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 100V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	nA	V <sub>EB</sub> = 5V
Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 100V
DC current transfer Static ratio (Note 8)	h <sub>FE</sub>	100 100 60 20	- - -	- 300 - -	-	$\begin{split} I_{C} &= 1 \text{mA}, V_{CE} = 10 \text{V} \\ I_{C} &= 250 \text{mA}, V_{CE} = 10 \text{V} \\ I_{C} &= 500 \text{mA}, V_{CE} = 10 \text{V} \\ I_{C} &= 1A, V_{CE} = 10 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	- -	- -	0.3 0.6	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(sat)}$	-	-	1.15	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-on Voltage (Note 8)	V <sub>BE(on)</sub>	-	-	1.0	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 10V
Transitional Frequency	f <sub>t</sub>	150	-	-	MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V f = 100MHz
Output capacitance	$C_{obo}$	-	-	10	pF	V <sub>CB</sub> = 10V, f = 1MHz,

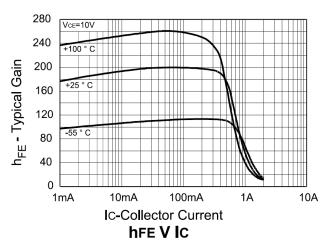
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

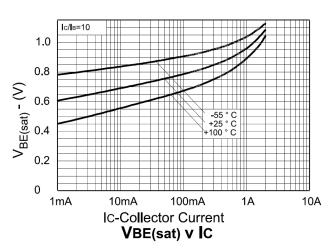


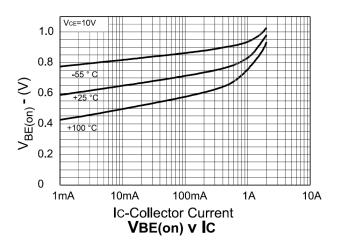
### Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)







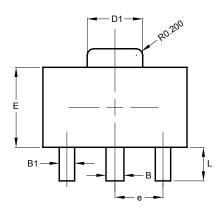


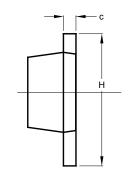


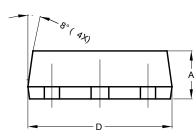


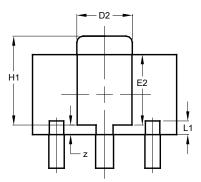
# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





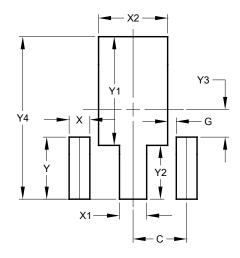




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

# **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$ 



Dimensions	Value			
	(in mm)			
С	1.500			
G	0.244			
Х	0.580			
X1	0.760			
X2	1.933			
Υ	1.730			
Y1	3.030			
Y2	1.500			
Y3	0.770			
Y4	4 530			



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